











SCAS643I - SEPTEMBER 2000 - REVISED OCTOBER 2017

**CDCV304** 

# CDCV304 200-MHz General-Purpose Clock Buffer, PCI-X Compliant

#### **Features**

- General-Purpose and PCI-X 1:4 Clock Buffer
- Operating Frequency
  - 0 MHz to 200 MHz General-Purpose
- Low Output Skew: <100 ps
- Distributes One Clock Input to One Bank of Four Outputs
- Output Enable Control that Drives Outputs Low when OE is Low
- Operates from Single 3.3-V Supply or 2.5-V Supply
- **PCI-X Compliant**
- 8-Pin TSSOP Package

## 2 Description

The CDCV304 is a high-performance, low-skew, general-purpose PCI-X compliant clock buffer. It distributes one input clock signal (CLKIN) to the output clocks (1Y[0:3]). It is specifically designed for use with PCI-X applications. The CDCV304 operates at 3.3 V and 2.5 V and is therefore compliant to the 3.3-V PCI-X specifications.

The CDCV304 is characterized for operation from -40°C to 85°C for automotive and industrial applications.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
CDCV304	TSSOP (8)	3.00 mm × 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

#### **Functional Block Diagram**

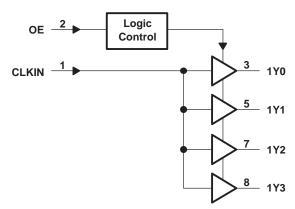




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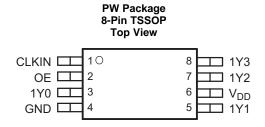
# 3 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision H (February 2011) to Revision I	Page
Changed datasheet layout	1
Added Junction temperature, T <sub>j, max</sub> 125 °C	
Changes from Revision G (January 2011) to Revision H	Page
Added missing characteristics graphs	6
Changes from Revision F (April 2009) to Revision G	Page
<ul> <li>Added ψ <sub>JT</sub> and ψ <sub>JB</sub> specs to the Thermal Information Table and changed R<sub>θJB</sub> and R<sub>ℓ</sub> respectively.</li> </ul>	



## 4 Pin Configuration and Functions



#### **Pin Functions**

PIN		1/0	DESCRIPTION	
NAME	NO.	I/O	DESCRIPTION	
1Y[0:3]	3, 5, 7, 8	0	Buffered output clocks	
CLKIN	1	I	Input reference frequency	
GND	4	Power	Ground	
OE	2	I	Output enable control	
$V_{DD}$	6	Power	Supply	

## 5 Specifications

## 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

	MIN	MAX	UNIT
Supply voltage range, V <sub>DD</sub>	-0.5	4.3	V
Input voltage range, V <sub>I</sub> (2) (3)	-0.5	V <sub>DD</sub> + 0.5	V
Output voltage range, V <sub>O</sub> <sup>(2) (3)</sup>	-0.5	V <sub>DD</sub> + 0.5	V
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0 or V <sub>I</sub> > V <sub>DD</sub> )	-50	50	mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>DD</sub> )	-50	50	mA
Continuous total output current, $I_O$ ( $V_O = 0$ to $V_{DD}$ )	-50	50	mA
Package thermal impedance, $\theta_{JA}$ : PW package		230.5	°C/W
Junction temperature, T <sub>j, max</sub>		125	°C
Storage temperature range T <sub>stg</sub>	-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(3) This value is limited to 4.6 V maximum.



### 5.2 Recommended Operating Conditions

		MIN	NOM MAX	UNIT
Supply voltage, V <sub>DD</sub>		2.3	3.6	V
Low-level input voltage, V <sub>IL</sub>			$0.3 \times V_{DD}$	V
High-level input voltage, V <sub>IH</sub>		0.7 x V <sub>DD</sub>		V
Input voltage, V <sub>I</sub>		0	$V_{DD}$	V
Lligh lovel output ourrent I	V <sub>DD</sub> = 2.5 V		-12	A
High-level output current, I <sub>OH</sub>	V <sub>DD</sub> = 3.3 V		-24	mA
Laurianal antoni anno at 1	V <sub>DD</sub> = 2.5 V		12	
Low-level output current, I <sub>OL</sub>	V <sub>DD</sub> = 3.3 V	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	mA	
Operating free-air temperature, T	Α.	-40	85	°C

#### 5.3 Thermal Information

				CDCV304	
	THERMAL METRIC <sup>(1)</sup>		THERMAL AIR FLOW (CFM)	PW (TSSOP)	UNIT
			1 2011 (01 111)	8 PINS	
			0	149	
	Junction-to-ambient thermal resistance	l link IX	150	142	
		High K	250	138	
Б			500	132	
$R_{\theta JA}$		Low K		230	°C/W
				185	
				170	
				150	
$R_{\theta JC(top)}$				43.7	
$R_{\theta JB}$				102	
ΨЈТ	Junction-to-top characterization parameter		1.8		
ΨЈВ	Junction-to-board characterization parameter			100.2	

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

#### 5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CO	NDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT	
$V_{IK}$	Input voltage	$V_{DD} = 3 V$ ,	$I_I = -18 \text{ mA}$			-1.2	V	
		$V_{DD} = 2.3 V$ ,	$I_{OH} = -8 \text{ mA}$	1.8				
		$V_{DD} = 2.3 V$ ,	$I_{OH} = -16 \text{ mA}$	1.5				
V <sub>OH</sub>	High-level output voltage	$V_{DD}$ = min to max,	$I_{OH} = -1 \text{ mA}$	V <sub>DD</sub> - 0.2			V	
		$V_{DD} = 3 V$ ,	$I_{OH} = -24 \text{ mA}$	2				
		$V_{DD} = 3 V$ ,	$I_{OH} = -12 \text{ mA}$	2.4				
		$V_{DD} = 2.3 V$ ,	$I_{OL} = 8 \text{ mA}$			0.5	V	
		$V_{DD} = 2.3 V$ ,	$I_{OL} = 16 \text{ mA}$			0.7		
$V_{OL}$	Low-level output voltage	$V_{DD}$ = min to max,	$I_{OL} = 1 \text{ mA}$			0.2		
		$V_{DD} = 3 V$ ,	$I_{OL} = 24 \text{ mA}$			0.8		
		$V_{DD} = 3 V$ ,	$I_{OL} = 12 \text{ mA}$			0.55		
	High level output ourrent	$V_{DD} = 3 V$ ,	$V_O = 1 V$	-50			mΑ	
I <sub>OH</sub>	High-level output current	$V_{DD} = 3.3 V$ ,	$V_0 = 1.65 \text{ V}$		-55		ША	
	Low lovel output ourrent	$V_{DD} = 3 V$ ,	V <sub>O</sub> = 2 V	60			mΛ	
I <sub>OL</sub>	Low-level output current	$V_{DD} = 3.3 \text{ V},$	V <sub>O</sub> = 1.65 V		70		mA	

All typical values are with respect to nominal  $V_{DD}$  and  $T_A$  = 25°C.



## **Electrical Characteristics (continued)**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP <sup>(1)</sup>	MAX	UNIT
$I_{\parallel}$	Input current	$V_I = V_O \text{ or } V_{DD}$				±5	μΑ
	I <sub>DD</sub> Dynamic current, see Figure 1	f = 67 MHz,	$V_{DD} = 2.7 \text{ V}$			28	A
IDD		f = 67 MHz,	$V_{DD} = 3.6 \text{ V}$			37	mA
Cı	Input capacitance	$V_{DD} = 3.3 \text{ V},$	$V_I = 0 \text{ V or } V_{DD}$		3		pF
Co	Output capacitance	$V_{DD} = 3.3 \text{ V},$	$V_I = 0 V \text{ or } V_{DD}$		3.2		pF

## 5.5 Timing Requirements

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f <sub>clk</sub>	Clock frequency		0		200	MHz

# 5.6 Switching Characteristics: $V_{DD} = 2.5 \text{ V} \pm 10\%$

 $V_{DD} = 2.5 \text{ V} \pm 10\%$ ,  $C_L = 10 \text{ pF}$  (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
t <sub>PLH</sub>	Low-to-high propagation delay	See Figure 4 and Figure 5	2	2.9	4.5	
t <sub>PHL</sub>	High-to-low propagation delay	See Figure 4 and Figure 5	2	3	4.5	ns
t <sub>sk(o)</sub>	Output skew <sup>(2)</sup>	See Figure 6		50	150	ps
t <sub>r</sub>	Output rise slew rate		1.5	2.2	4	V/ns
t <sub>f</sub>	Output fall slew rate		1.5	2.2	4	V/ns

## 5.7 Switching Characteristics: $V_{DD} = 3.3 \text{ V} \pm 10\%$

 $V_{DD} = 3.3 \text{ V} \pm 10\%$ ,  $C_L = 10 \text{ pF}$  (unless otherwise noted)

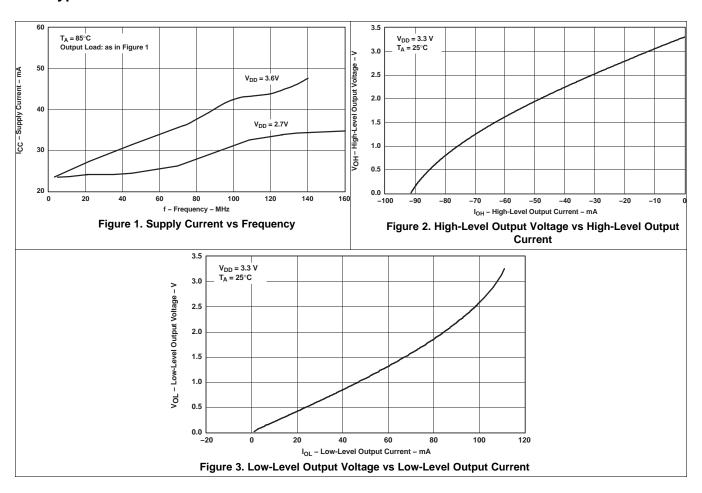
	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
t <sub>PLH</sub>	Low-to-high propagation delay	Con Figure 4 and Figure 5	1.8	2.4	3	
t <sub>PHL</sub>	High-to-low propagation delay	See Figure 4 and Figure 5	1.8	2.5	3	ns
t <sub>sk(o)</sub>	Output skew <sup>(2)</sup>			50	100	ps
	Additional and the form install a sector AVO	12 kHz to 5 MHz, f <sub>out</sub> = 30.72 MHz		63		
t <sub>jitter</sub>	Additive phase jitter from input to output 1Y0	12 kHz to 20 MHz, f <sub>out</sub> = 125 MHz		56		fs rms
t <sub>sk(p)</sub>	Pulse skew	$V_{IH} = V_{DD}, V_{IL} = 0 V$			150	ps
t <sub>sk(pr)</sub>	Process skew			0.2	0.3	ns
t <sub>sk(pp)</sub>	Part-to-part skew			0.25	0.4	ns
	Olash kish dan ana Finan 7	66 MHz	6			
t <sub>high</sub>	Clock high time, see Figure 7	140 MHz	3			ns
	Olash Januarian and Firema 7	66 MHz	6			
t <sub>low</sub>	Clock low time, see Figure 7	140 MHz	3			ns
t <sub>r</sub>	Output rise slew rate <sup>(3)</sup>	V <sub>O</sub> = 0.4 V to 2 V	1.5	2.7	4	V/ns
t <sub>f</sub>	Output fall slew rate <sup>(3)</sup>	V <sub>O</sub> = 2 V to 0.4 V	1.5	2.7	4	V/ns

 $<sup>\</sup>begin{array}{ll} \text{(1)} & \text{All typical values are with respect to nominal $V_{DD}$.} \\ \text{(2)} & \text{The $t_{sk(o)}$ specification is only valid for equal loading of all outputs.} \end{array}$ 

 <sup>(1)</sup> All typical values are with respect to nominal V<sub>DD</sub>.
 (2) The t<sub>sk(o)</sub> specification is only valid for equal loading of all outputs.
 (3) This symbol is according to PCI-X terminology.



## 5.8 Typical Characteristics





#### **6 Parameter Measurement Information**

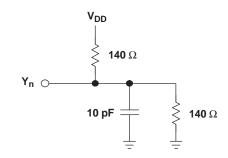


Figure 4. Test Load Circuit

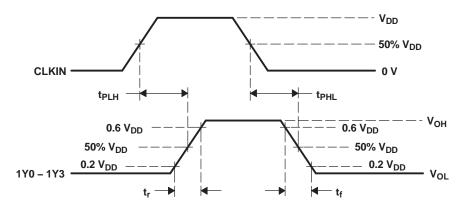


Figure 5. Voltage Waveforms Propagation Delay (tpd) Measurements

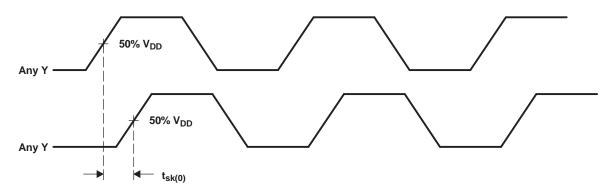
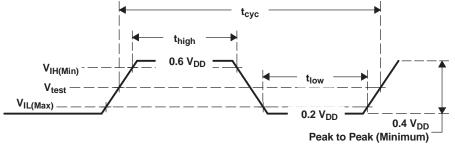


Figure 6. Output Skew

PARAMETER	VALUE	UNIT
V <sub>IH(Min)</sub>	0.5 V <sub>DD</sub>	V
V <sub>IL(Max)</sub>	0.35 V <sub>DD</sub>	V
V <sub>test</sub>	$0.4~V_{DD}$	V



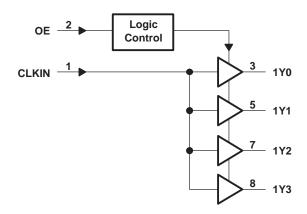
A. All parameters in Figure 7 are according to PCI-X 1.0 specifications.

Figure 7. Clock Waveform



# 7 Detailed Description

# 7.1 Functional Block Diagram



#### 7.2 Device Functional Modes

**Table 1. Function Table** 

INP	INPUTS					
CLKIN	OE	1Y[0:3]				
L	L	L				
Н	L	L				
L	Н	L				
Н	Н	Н				

Product Folder Links: CDCV304

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## 8 Device and Documentation Support

#### 8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 8.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 8.3 Trademarks

E2E is a trademark of Texas Instruments.

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#### 8.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 8.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

## 9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow	Peak reflow	
						(4)	(5)		
CDCV304PW	Active	Production	TSSOP (PW)   8	150   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304
CDCV304PW.A	Active	Production	TSSOP (PW)   8	150   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304
CDCV304PWG4	Active	Production	TSSOP (PW)   8	150   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304
CDCV304PWR	Active	Production	TSSOP (PW)   8	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304
CDCV304PWR.A	Active	Production	TSSOP (PW)   8	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304
CDCV304PWRG4	Active	Production	TSSOP (PW)   8	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## PACKAGE OPTION ADDENDUM

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#### OTHER QUALIFIED VERSIONS OF CDCV304:

● Enhanced Product : CDCV304-EP

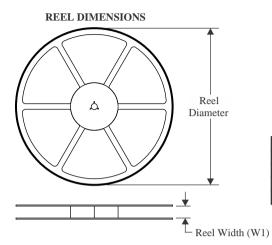
NOTE: Qualified Version Definitions:

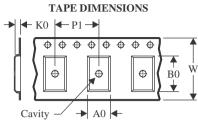
• Enhanced Product - Supports Defense, Aerospace and Medical Applications

# **PACKAGE MATERIALS INFORMATION**

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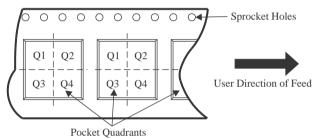
#### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

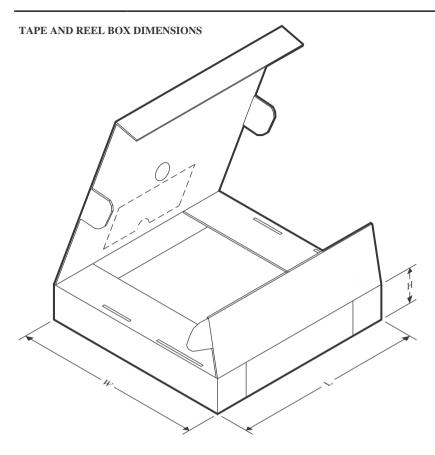


#### \*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CDCV304PWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

# **PACKAGE MATERIALS INFORMATION**

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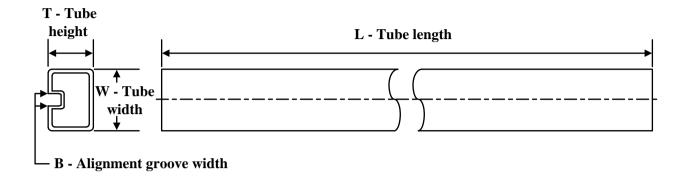
#### \*All dimensions are nominal

Ì	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
ı	CDCV304PWR	TSSOP	PW	8	2000	353.0	353.0	32.0	

# **PACKAGE MATERIALS INFORMATION**

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#### **TUBE**

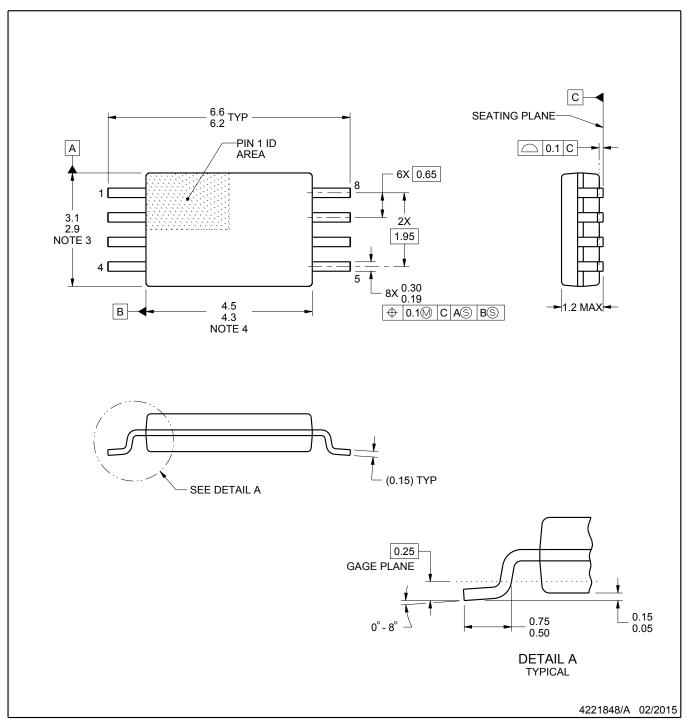


#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CDCV304PW	PW	TSSOP	8	150	530	10.2	3600	3.5
CDCV304PW.A	PW	TSSOP	8	150	530	10.2	3600	3.5
CDCV304PWG4	PW	TSSOP	8	150	530	10.2	3600	3.5



SMALL OUTLINE PACKAGE



#### NOTES:

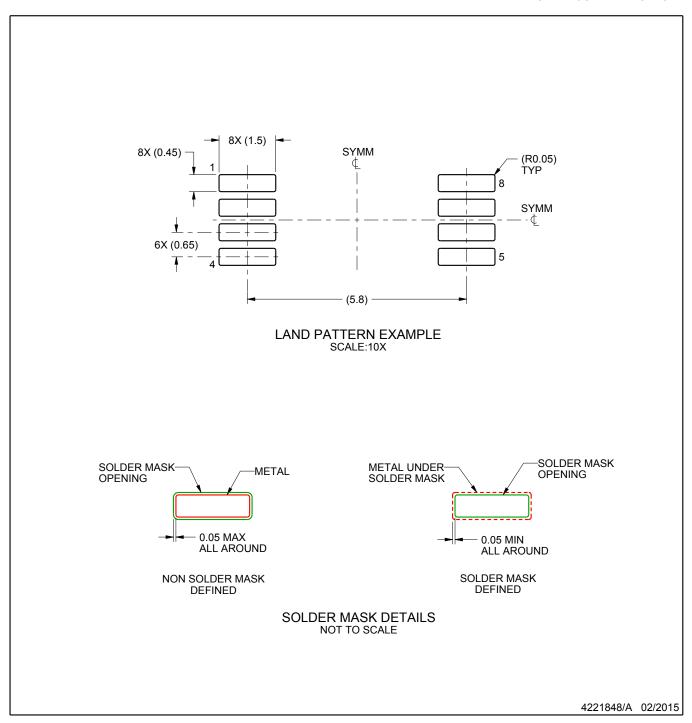
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



SMALL OUTLINE PACKAGE



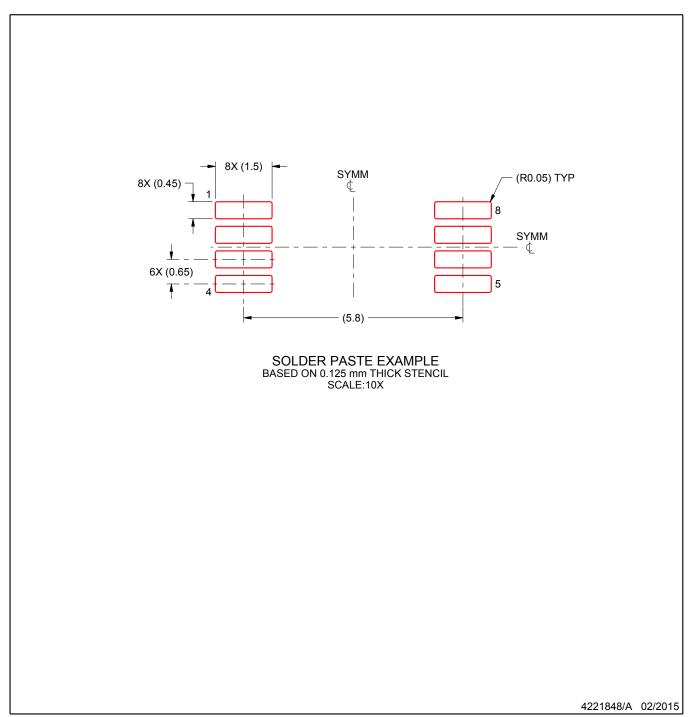
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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